

4V Drive Nch MOSFET

RQ1E075XN

● Structure

Silicon N-channel MOSFET

● Features

- 1) Low on-resistance.
- 2) Built-in G-S Protection Diode.
- 3) Small Surface Mount Package (TSMT8).

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	TCR
	Basic ordering unit (pieces)	3000
RQ1E075XN		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DS}	30	V
Gate-source voltage		V_{GS}	± 20	V
Drain current	Continuous	I_D	± 7.5	A
	Pulsed	I_{DP} *1	± 30	A
Source current (Body Diode)	Continuous	I_S	1.25	A
	Pulsed	I_{SP} *1	30	A
Power dissipation		P_D *2	1.5	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

*1 $P_w \leq 10 \mu s$, Duty cycle $\leq 1\%$

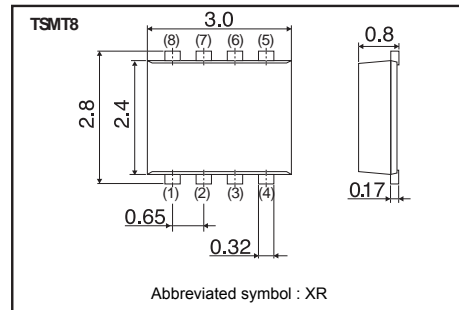
*2 Mounted on a ceramic board.

● Thermal resistance

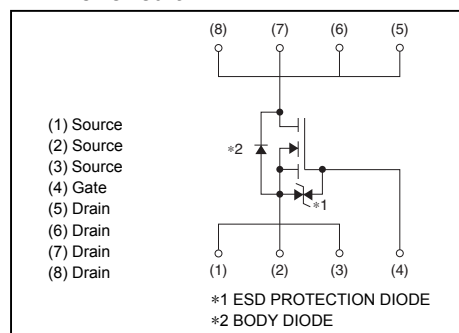
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th(ch-a)}$ *	83.3	°C / W

*Mounted on a ceramic board.

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	± 10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	30	-	-	V	$I_D = 1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	-	-	1	μA	$V_{DS} = 30V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	1.0	-	2.5	V	$V_{DS} = 10V, I_D = 1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	12	17	m Ω	$I_D = 7.5A, V_{GS} = 10V$
		-	17	24		$I_D = 7.5A, V_{GS} = 4.5V$
		-	19	27		$I_D = 7.5A, V_{GS} = 4.0V$
Forward transfer admittance	$ Y_{fs} ^*$	4.5	-	-	S	$I_D = 7.5A, V_{DS} = 10V$
Input capacitance	C_{iss}	-	440	-	pF	$V_{DS} = 10V$
Output capacitance	C_{oss}	-	170	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	-	85	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	7	-	ns	$I_D = 3.75A, V_{DD} = 15V$
Rise time	t_r^*	-	25	-	ns	$V_{GS} = 10V$
Turn-off delay time	$t_{d(off)}^*$	-	35	-	ns	$R_L = 4.0\Omega$
Fall time	t_f^*	-	7	-	ns	$R_G = 10\Omega$
Total gate charge	Q_g^*	-	6.8	-	nC	$I_D = 7.5A, V_{DD} = 15V$
Gate-source charge	Q_{gs}^*	-	1.6	-	nC	$V_{GS} = 5V$
Gate-drain charge	Q_{gd}^*	-	2.6	-	nC	

*Pulsed

● Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	1.2	V	$I_s = 7.5A, V_{GS} = 0V$

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical Output Characteristics(I)

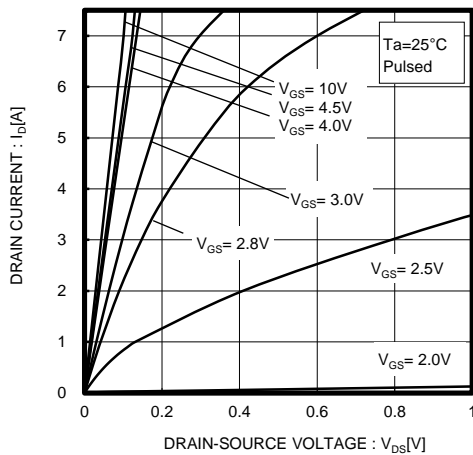


Fig.2 Typical Output Characteristics(II)

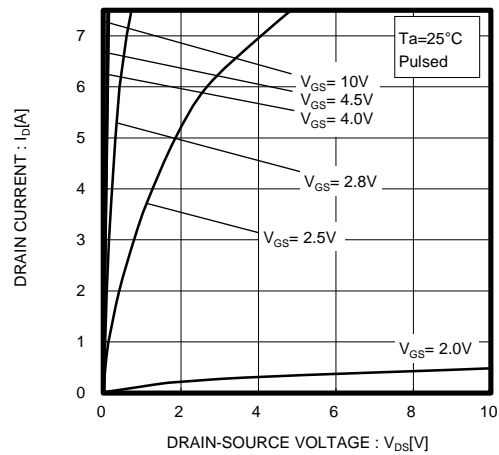


Fig.3 Typical Transfer Characteristics

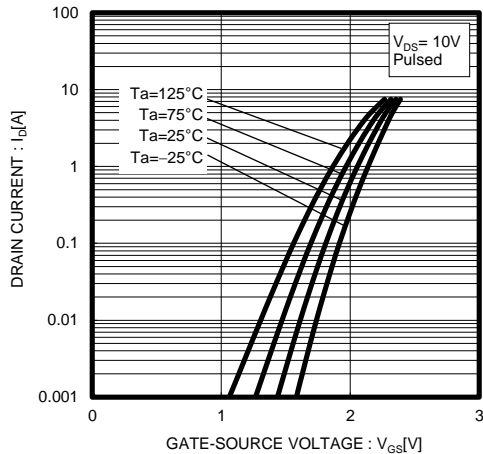


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current(I)

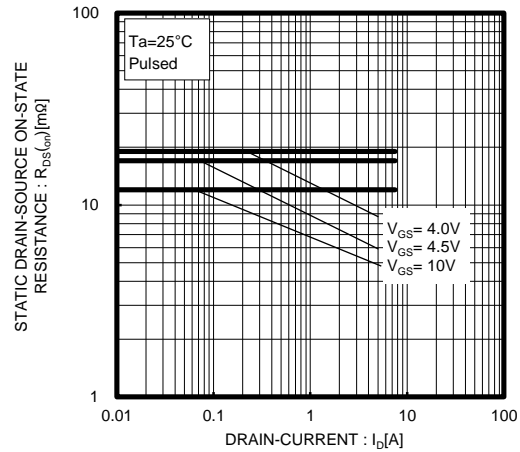


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

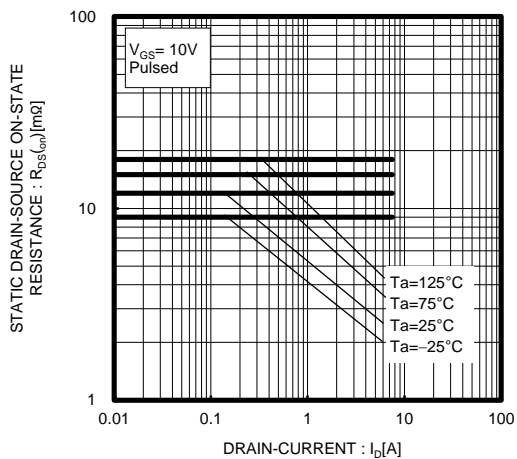


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

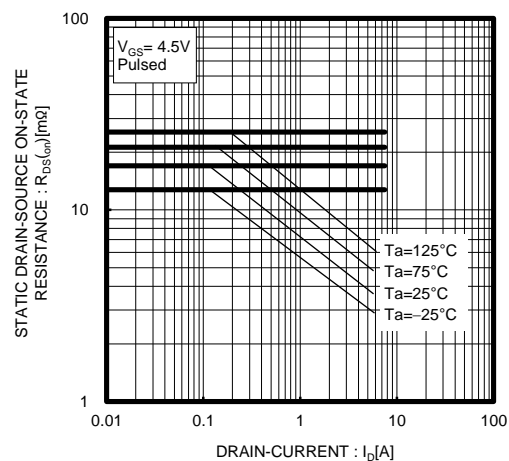


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (IV)

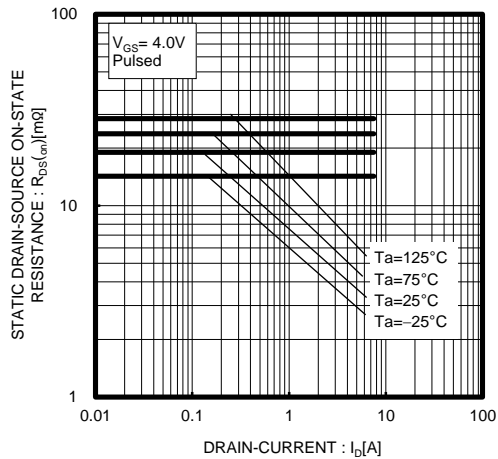


Fig.8 Forward Transfer Admittance vs. Drain Current

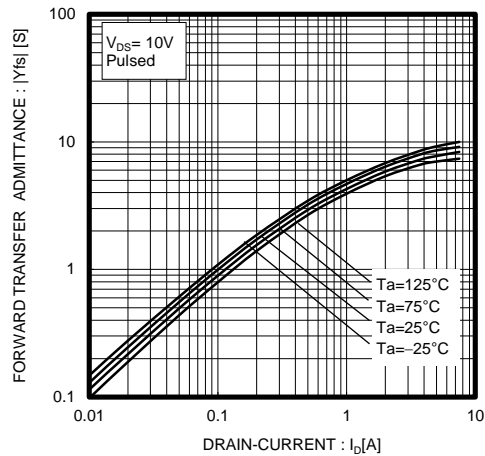


Fig.9 Reverse Drain Current vs. Source-Drain Voltage

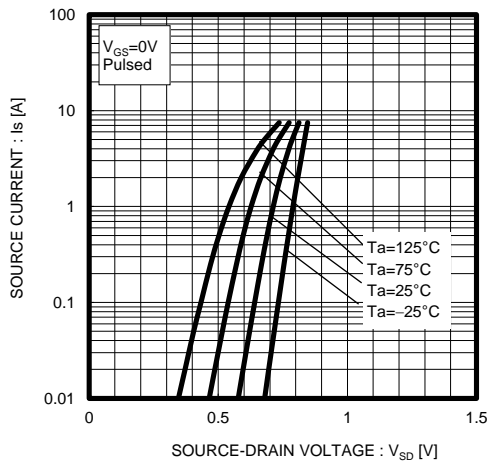


Fig.10 Static Drain-Source On-State Resistance vs. Gate Source Voltage

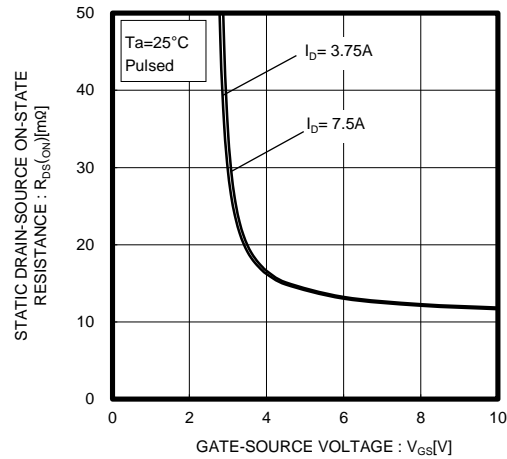


Fig.11 Switching Characteristics

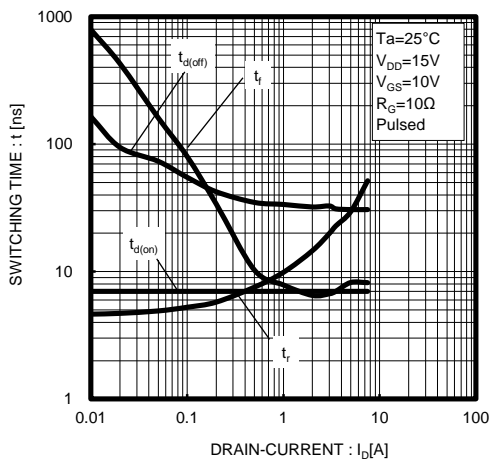


Fig.12 Dynamic Input Characteristics

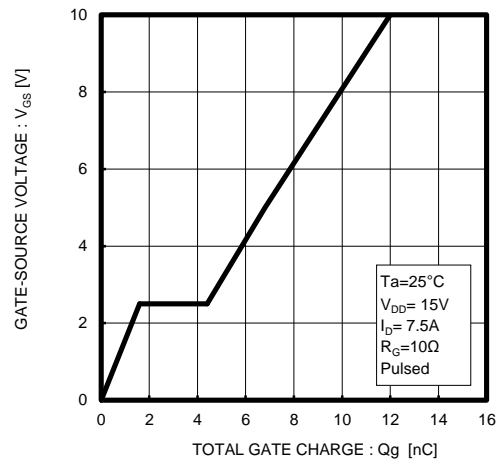


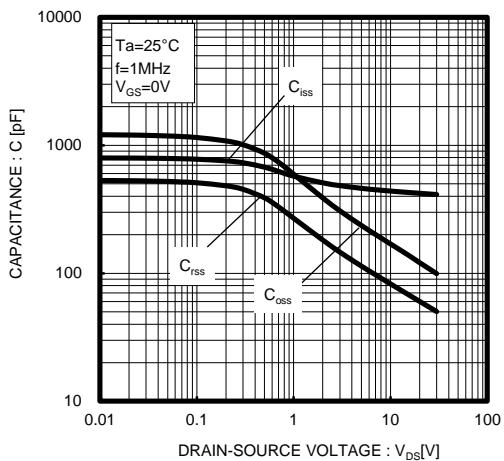
Fig.13 Typical Capacitance
vs. Drain-Source Voltage

Fig.14 Maximum Safe Operating Area

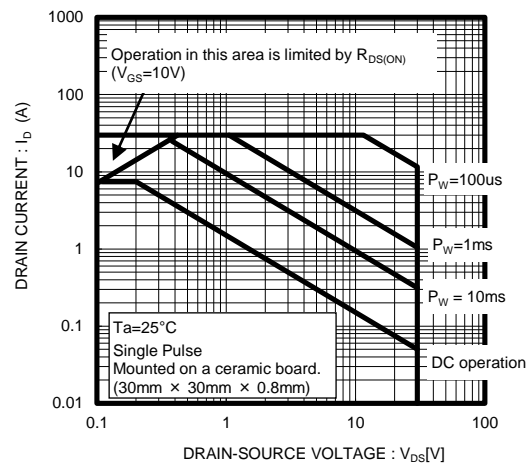
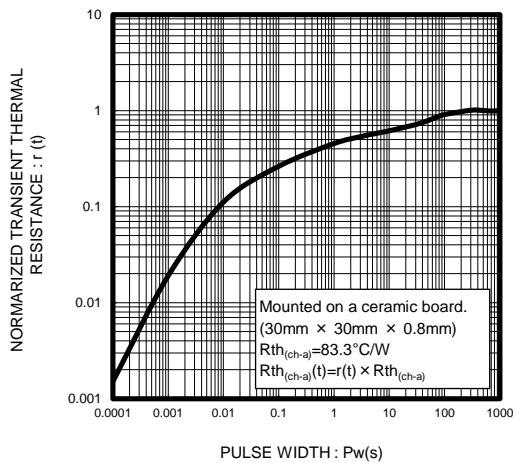


Fig.15 Normalized Transient Thermal Resistance vs. Pulse Width



● Measurement circuits

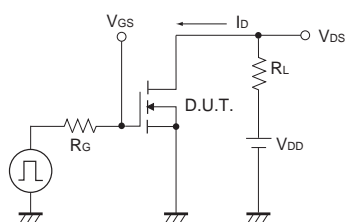


Fig.1-1 Switching Time Measurement Circuit

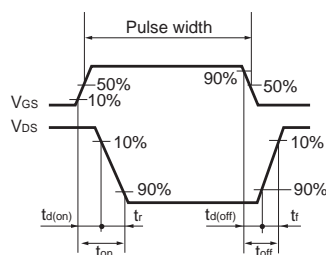


Fig.1-2 Switching Waveforms

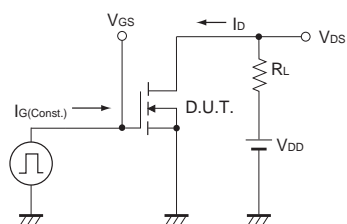


Fig.2-1 Gate Charge Measurement Circuit

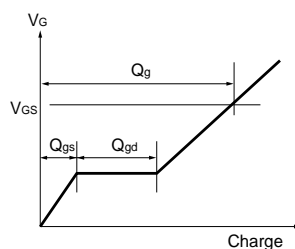


Fig.2-2 Gate Charge Waveform

● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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